MJD2955 (PNP), MJD3055 (NPN)

Complementary Power Transistors

DPAK for Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("–1" Suffix)
- Electrically Similar to MJE2955 and MJE3055
- High Current Gain–Bandwidth Product
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|--|-----------------------------------|---------------|-----------|
| Collector-Emitter Voltage | V _{CEO} | 60 | Vdc |
| Collector-Base Voltage | V _{CB} | 70 | Vdc |
| Emitter-Base Voltage | V _{EB} | 5 | Vdc |
| Collector Current | ۱ _C | 10 | Adc |
| Base Current | I _B | 6 | Adc |
| Total Power Dissipation @ T _C = 25°C Derate above 25°C | P _D † | 20 0.16 | W W/°C |
| Total Power Dissipation (Note 1) @ $T_A = 25^{\circ}C$ Derate above 25°C | P _D | 1.75 0.014 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |
| ESD – Human Body Model | HBM | 3B | V |
| ESD – Machine Model | MM | С | V |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

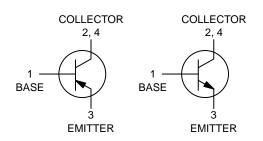


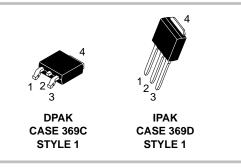
ON Semiconductor®

http://onsemi.com

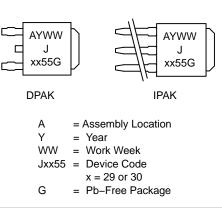
SILICON POWER TRANSISTORS 10 AMPERES 60 VOLTS, 20 WATTS







MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MJD2955 (PNP), MJD3055 (NPN)

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------|------|------|
| Thermal Resistance, Junction-to-Case | $R_{	extsf{	heta}JC}$ | 6.25 | °C/W |
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{	hetaJA}$ | 71.4 | °C/W |

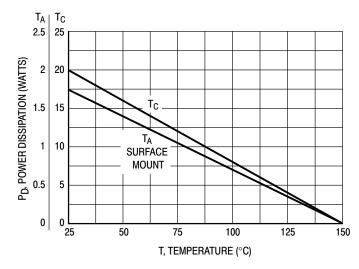
2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

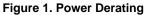
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

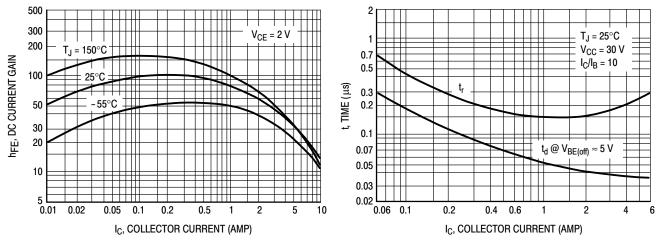
| V _{CEO(sus)} | | · | |
|-----------------------|--|-----------|--|
| V _{CEO(sus)} | | <u> </u> | |
| | 60 | - | Vdc |
| I _{CEO} | _ | 50 | μAdc |
| ICEX | | 0.02 2 | mAdc |
| Ісво | | 0.02 2 | mAdc |
| I _{EBO} | _ | 0.5 | mAdc |
| · · · · | | | <u> </u> |
| h _{FE} | 20 5 | 100 | _ |
| V _{CE(sat)} | | 1.1 8 | Vdc |
| V _{BE(on)} | _ | 1.8 | Vdc |
| | | | |
| f _T | 2 | - | MHz |
| - | I _{CEX} I _{CBO} I _{EBO} N _{FE} V _{CE(sat)} V _{BE(on)} | | $\begin{array}{c c c c c c c } & - & 50 \\ \hline l_{CEX} & - & 0.02 \\ - & 2 \\ \hline l_{CBO} & - & 0.02 \\ - & 2 \\ \hline l_{EBO} & - & 0.5 \\ \hline \end{array}$ |

3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

TYPICAL CHARACTERISTICS

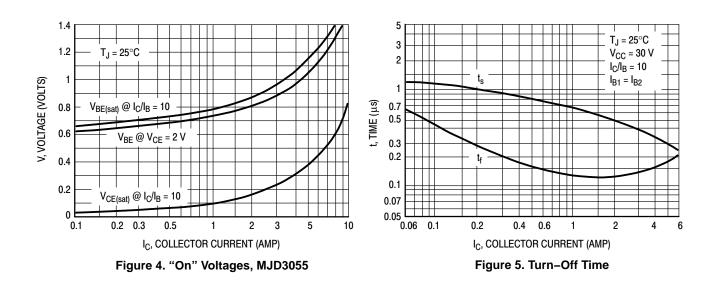












MJD2955 (PNP), MJD3055 (NPN)

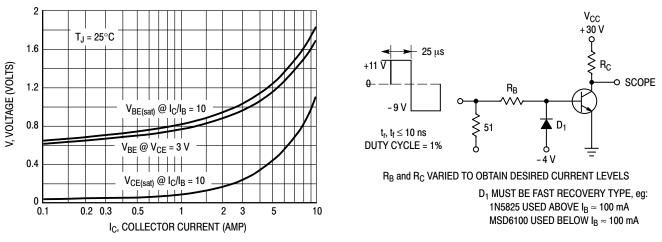
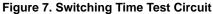
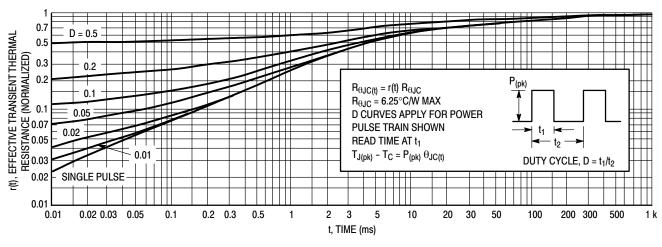
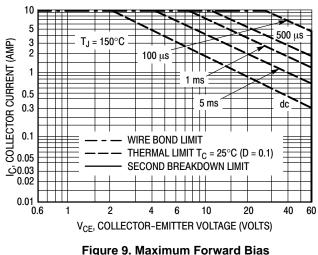


Figure 6. "On" Voltages, MJD2955









Safe Operating Area

Forward Bias Safe Operating Area Information

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

MJD2955 (PNP), MJD3055 (NPN)

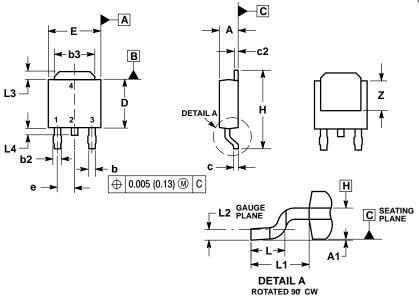
ORDERING INFORMATION

| Device | Package Type | Package | Shipping [†] |
|---------------------------|---------------------------|---------|-----------------------|
| MJD2955G | DPAK (Pb–Free) | 369C | 75 Units / Rail |
| MJD2955-1G | IPAK (Pb–Free) | 369D | 75 Units / Rail |
| MJD2955T4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel |
| NJVMJD2955T4G* | DPAK (Pb–Free) | 369C | 2,500 / Tape & Reel |
| MJD3055G | JD3055G DPAK (Pb–Free) | | 75 Units / Rail |
| MJD3055T4G DPAK (Pb-Free) | | 369C | 2,500 / Tape & Reel |
| NJVMJD3055T4G* | DPAK (Pb–Free) | 369C | 2,500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE) CASE 369C ISSUE D



NOTES:

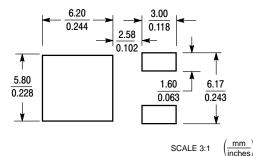
- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
 DATUMS A AND B ARE DETERMINED AT DATUM
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

| | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.086 | 0.094 | 2.18 | 2.38 |
| A1 | 0.000 | 0.005 | 0.00 | 0.13 |
| b | 0.025 | 0.035 | 0.63 | 0.89 |
| b2 | 0.030 | 0.045 | 0.76 | 1.14 |
| b3 | 0.180 | 0.215 | 4.57 | 5.46 |
| С | 0.018 | 0.024 | 0.46 | 0.61 |
| c2 | 0.018 | 0.024 | 0.46 | 0.61 |
| D | 0.235 | 0.245 | 5.97 | 6.22 |
| Е | 0.250 | 0.265 | 6.35 | 6.73 |
| е | 0.090 BSC | | 2.29 BSC | |
| н | 0.370 | 0.410 | 9.40 | 10.41 |
| L | 0.055 | 0.070 | 1.40 | 1.78 |
| L1 | 0.108 REF | | 2.74 | REF |
| L2 | 0.020 BSC | | 0.51 BSC | |
| L3 | 0.035 | 0.050 | 0.89 | 1.27 |
| L4 | | 0.040 | | 1.01 |
| Ζ | 0.155 | | 3.93 | |

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER 4. COLLECTOR

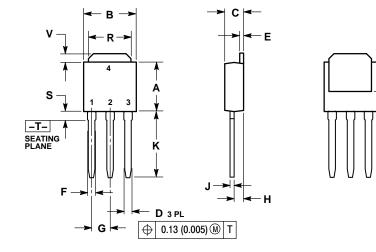
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

| | INCHES | | MILLIM | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.235 | 0.245 | 5.97 | 6.35 |
| В | 0.250 | 0.265 | 6.35 | 6.73 |
| С | 0.086 | 0.094 | 2.19 | 2.38 |
| D | 0.027 | 0.035 | 0.69 | 0.88 |
| E | 0.018 | 0.023 | 0.46 | 0.58 |
| F | 0.037 | 0.045 | 0.94 | 1.14 |
| G | 0.090 BSC | | 2.29 BSC | |
| Н | 0.034 | 0.040 | 0.87 | 1.01 |
| J | 0.018 | 0.023 | 0.46 | 0.58 |
| ĸ | 0.350 | 0.380 | 8.89 | 9.65 |
| R | 0.180 | 0.215 | 4.45 | 5.45 |
| S | 0.025 | 0.040 | 0.63 | 1.01 |
| ۷ | 0.035 | 0.050 | 0.89 | 1.27 |
| Ζ | 0.155 | | 3.93 | |

STYLE 1: PIN 1. BASE

z

COLLECTOR
 EMITTER

4. COLLECTOR

ON Semiconductor and **UD** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. SCILLC does not designed, intended, or authorized for use as components instended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal linjury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and i

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: ON Semiconductor Website: www.onsemi.com

Crder Literature: http://www.onsemi.com/orderlit

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050

For additional information, please contact your local Sales Representative 单击下面可查看定价,库存,交付和生命周期等信息

>>ON Semiconductor(安森美)